Low Noise Transistor

NPN Silicon

Features

• Pb-Free Package is Available

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|--------------------------------|------------------|-------|------|
| Collector – Emitter Voltage | V _{CEO} | 60 | Vdc |
| Collector-Base Voltage | V _{CBO} | 60 | Vdc |
| Emitter-Base Voltage | V _{EBO} | 6.0 | Vdc |
| Collector Current – Continuous | Ι _C | 100 | mAdc |

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|--|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR–5 Board, (Note 1) T _A = 25°C Derate above 25°C | P _D | 225 1.8 | mW m₩/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W |
| Total Device Dissipation Alumina Substrate, (Note 2) $T_A = 25^{\circ}C$ Derate above 25°C | P _D | 300 2.4 | mW m₩/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 417 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C |

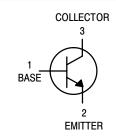
Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

1. $FR-5 = 1.0 \times 0.75 \times 0.062$ in. 2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.



ON Semiconductor®

http://onsemi.com





SOT-23 (TO-236) **CASE 318 STYLE 6**

MARKING DIAGRAM



1U = Device Code

- M = Date Code*
- . = Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping [†] | |
|--------------|---------------------|-----------------------|--|
| MMBT2484LT1 | SOT-23 | 3,000 / Tape & Reel | |
| MMBT2484LT1G | SOT–23 (Pb–Free) | 3,000 / Tape & Reel | |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25° C unless otherwise noted)

| Characteristic | Symbol | Min | Max | Unit |
|---|----------------------|----------|----------|--------------|
| OFF CHARACTERISTICS | | | | |
| Collector – Emitter Breakdown Voltage ($I_C = 10 \text{ mAdc}, I_B = 0$) | V _{(BR)CEO} | 60 | _ | Vdc |
| Collector – Base Breakdown Voltage $(I_C = 10 \ \mu Adc, I_E = 0)$ | V _{(BR)CBO} | 60 | _ | Vdc |
| Emitter – Base Breakdown Voltage ($I_E = 10 \ \mu Adc, I_C = 0$) | V _{(BR)EBO} | 5.0 | _ | Vdc |
| Collector Cutoff Current $(V_{CB} = 45 \text{ Vdc}, I_E = 0)$ $(V_{CB} = 45 \text{ Vdc}, I_E = 0, T_A = 150^{\circ}\text{C})$ | I _{CBO} | | 10 10 | nAdc μAdc |
| Emitter Cutoff Current ($V_{EB} = 5.0 \text{ Vdc}, I_C = 0$) | I _{EBO} | _ | 10 | nAdc |
| ON CHARACTERISTICS | · | | | |
| DC Current Gain ($I_C = 1.0 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) ($I_C = 10 \text{ mAdc}, V_{CE} = 5.0 \text{ Vdc}$) | h _{FE} | 250 - | _ 800 | - |
| Collector – Emitter Saturation Voltage ($I_C = 1.0$ mAdc, $I_B = 0.1$ mAdc) | V _{CE(sat)} | _ | 0.35 | Vdc |
| Base – Emitter On Voltage (I _C = 1.0 mAdc, V _{CE} = 5.0 Vdc) | V _{BE(on)} | - | 0.95 | Vdc |
| SMALL-SIGNAL CHARACTERISTICS | · | | | |
| Output Capacitance $(V_{CB} = 5.0 \text{ Vdc}, I_E = 0, f = 1.0 \text{ MHz})$ | C _{obo} | _ | 6.0 | pF |
| Input Capacitance $(V_{EB} = 0.5 \text{ Vdc}, I_C = 0, f = 1.0 \text{ MHz})$ | C _{ibo} | _ | 6.0 | pF |
| Noise Figure (I _C = 10 μ Adc, V _{CE} = 5.0 Vdc, R _S = 10 kΩ, f = 1.0 kHz, BW = 200 Hz) | NF | _ | 3.0 | dB |

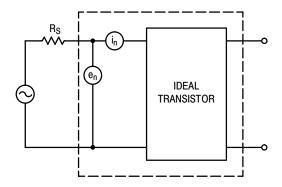
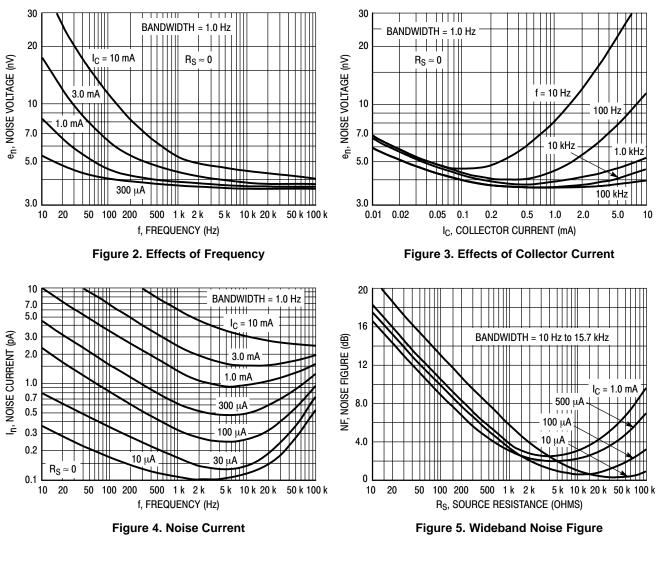


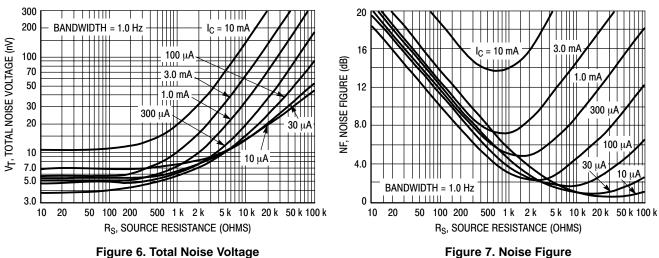
Figure 1. Transistor Noise Model

NOISE CHARACTERISTICS

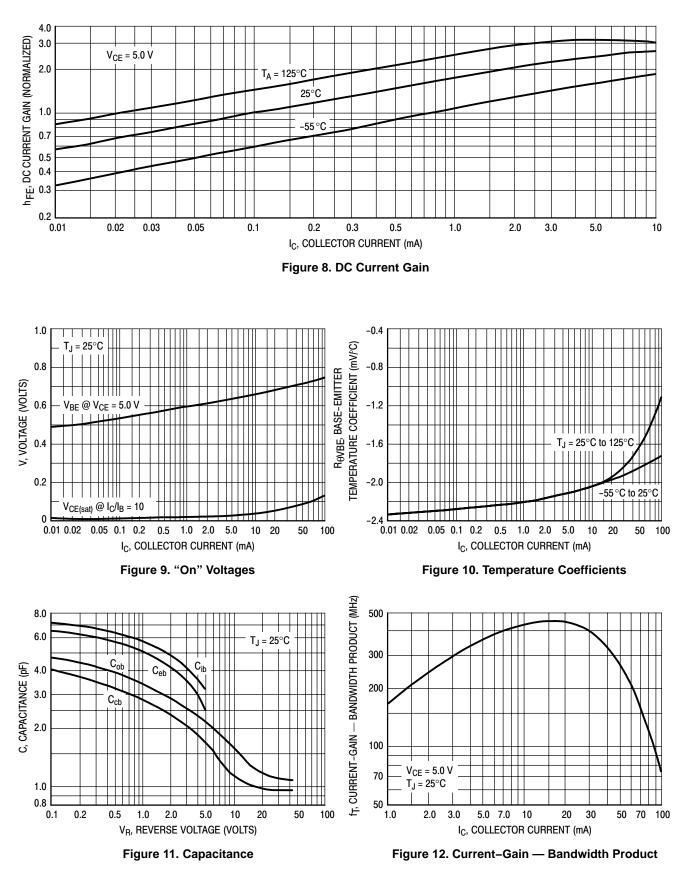
 $(V_{CE} = 5.0 \text{ Vdc}, T_A = 25^{\circ}C)$

NOISE VOLTAGE



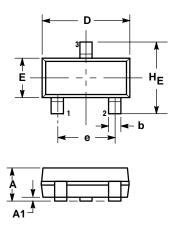


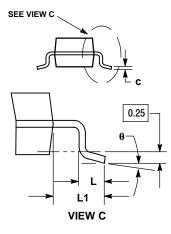
100 Hz NOISE DATA



PACKAGE DIMENSIONS

SOT-23 (TO-236) CASE 318-08 **ISSUE AN**





NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD

THICKNESS IS THE MINIMUM THICKNESS OF

BASE MATERIAL.

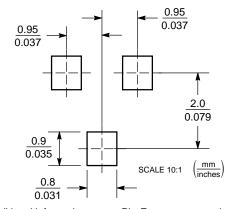
4. 318–01 THRU –07 AND –09 OBSOLETE, NEW STANDARD 318–08.

| | MILLIMETERS | | | INCHES | | |
|-----|-------------|------|------|--------|-------|-------|
| DIM | MIN | NOM | MAX | MIN | NOM | MAX |
| Α | 0.89 | 1.00 | 1.11 | 0.035 | 0.040 | 0.044 |
| A1 | 0.01 | 0.06 | 0.10 | 0.001 | 0.002 | 0.004 |
| b | 0.37 | 0.44 | 0.50 | 0.015 | 0.018 | 0.020 |
| С | 0.09 | 0.13 | 0.18 | 0.003 | 0.005 | 0.007 |
| D | 2.80 | 2.90 | 3.04 | 0.110 | 0.114 | 0.120 |
| E | 1.20 | 1.30 | 1.40 | 0.047 | 0.051 | 0.055 |
| е | 1.78 | 1.90 | 2.04 | 0.070 | 0.075 | 0.081 |
| L | 0.10 | 0.20 | 0.30 | 0.004 | 0.008 | 0.012 |
| L1 | 0.35 | 0.54 | 0.69 | 0.014 | 0.021 | 0.029 |
| HE | 2.10 | 2.40 | 2.64 | 0.083 | 0.094 | 0.104 |

STYLE 6:

PIN 1. BASE 2. EMITTER 3. COLLECTOR

SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

ON Semiconductor and 💷 are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

PUBLICATION ORDERING INFORMATION

LITERATURE FULFILLMENT

Literature Distribution Center for ON Semiconductor P.O. Box 61312, Phoenix, Arizona 85082-1312 USA Phone: 480-829-7710 or 800-344-3860 Toll Free USA/Canada Fax: 480-829-7709 or 800-344-3867 Toll Free USA/Canada Email: orderlit@onsemi.com

N. American Technical Support: 800-282-9855 Toll Free USA/Canada

Japan: ON Semiconductor, Japan Customer Focus Center 2-9-1 Kamimeguro, Meguro-ku, Tokyo, Japan 153-0051 Phone: 81-3-5773-3850

ON Semiconductor Website: http://onsemi.com

Order Literature: http://www.onsemi.com/litorder

For additional information, please contact your local Sales Representative.